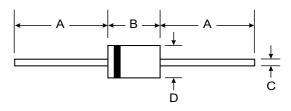


SCHOTTKY BARRIER DIODE

Features

- High Reverse Breakdown Voltage
- Low Turn-On Voltage
- Guard Ring Construction for Transient Protection



Mechanical Data

Case: DO-35, Plastic

• Leads: Solderable per MIL-STD-202,

Method 208

Marking: Type NumberPolarity: Cathode BandWeight: 0.13 grams (approx.)

DO-35						
Dim	Min	Max				
Α	25.40	_				
В	_	4.00				
С	_	0.60				
D	- A-	2.00				
All Dimensions in mm						

Maximum Ratings @ TA = 25°C unless otherwise specified

Characteristic	Symbol	BAT46	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	V	
Forward Continuous Current (Note 1)	I _{FM}	150	mA	
Average Rectified Output Current (Note 1)	lo	75	mA	
Repetitive Peak Forward Current (Note 1) @ t ≤ 1.0s	I _{FRM}	350	mA	
Non-Repetitive Peak Forward Surge Current @ t = 10ms	I _{FSM}	750	mA	
Power Dissipation (Note 1)	P _d	200	mW	
Thermal Resistance, Junction to Ambient Air (Note 1)	R ₀ JA	500	K/W	
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +125	°C	

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage	V _{(BR)R}	100	_	_	V	I _{RS} = 10μA (pulses)
Reverse Leakage Current (Note 2)	I _R	_	_	0.5 5.0 0.8 7.5 2.0 15 5.0	μΑ	$\begin{array}{c} V_R = 1.5V \\ V_R = 1.5V, T_j = 60^{\circ}C \\ V_R = 10V \\ V_R = 10V, T_j = 60^{\circ}C \\ V_R = 50V, T_j = 60^{\circ}C \\ V_R = 75V \\ V_R = 75V, T_j = 60^{\circ}C \\ \end{array}$
Forward Voltage Drop (Note 2)	V _F	_	_	0.25 0.45 1.00	V	$I_F = 0.1 \text{mA}$ $I_F = 10 \text{mA}$ $I_F = 250 \text{mA}$
Junction Capacitance	Cj	_	10 6.0	_	pF	V _R = 0V, f = 1.0MHz V _R = 1.0V, f = 1.0MHz

Notes: 1. Valid provided that electrodes are kept at ambient temperature.

2. $t < 300 \mu s$, Duty Cycle < 2%.